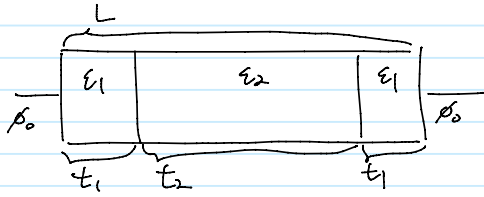


2020년 9월 29일 화요일      오후 3:46

20184060 Jicheol Kim



$$\frac{d}{dx} \left( \varepsilon(x) \frac{d\phi(x)}{dx} \right) = b(x) \quad \text{on } K,$$

$$\frac{d}{dx} \left( \varepsilon(x) \frac{d\phi(x)}{dx} \right) = b(x) \quad \text{or } |, \\ \varepsilon(x) = \begin{cases} \varepsilon_1 & \text{for } 0 \leq x < t_1 \\ \varepsilon_2 & \text{for } t_1 \leq x < t_1 + t_2 \\ \varepsilon_1 & \text{for } t_1 + t_2 \leq x < L \end{cases}, \quad b(x) = \begin{cases} \phi_0 & \text{at } x=0 \\ 0 & \text{for } 0 < x < t_1 \\ \bar{\rho} N_{acc} & \text{for } t_1 < x < t_1 + t_2 \\ 0 & \text{for } t_1 + t_2 < x < L \\ \phi_0 & \text{at } x=L \end{cases} \quad \text{when we take the depletion approximation.} \\ \phi(0) = \phi(L) = 0.$$

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If we add an electron (hole) density to the  $b(x)$  of the depletion approximation,

$$b(x) = \begin{cases} \phi_0 + V_G & \text{at } x=0 \\ 0 & \text{for } 0 < x < t_1 \\ gN_{\text{acc}} + g(N(x) - p(x)) & \text{for } t_1 < x < t_1 + t_2 \\ 0 & \text{for } t_1 + t_2 < x < L \\ \phi_0 + V_G & \text{at } x=L \end{cases}$$

Where  $V_G$  is a gate voltage,  $n(x)$  ( $p(x)$ ) is an electron (hole) density.

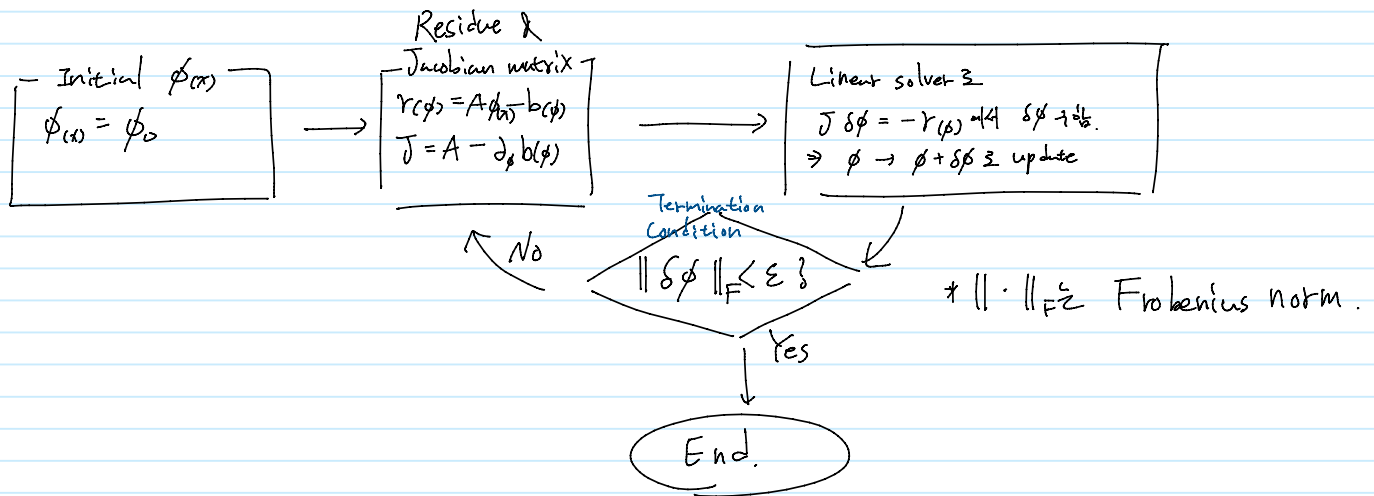
$$\begin{cases} n(x) = N_c \exp\left(-\frac{E_c - E_i}{k_B T}\right) \exp\left(\frac{q\phi}{k_B T}\right) \\ p(x) = N_c \exp\left(-\frac{E_i - E_v}{k_B T}\right) \exp\left(-\frac{q\phi}{k_B T}\right) \end{cases} \Rightarrow \mathcal{L}(n(x) - p(x)) = 2\mathcal{L}N_c e^{\frac{E_c - E_v}{k_B T}} \sinh\left(\frac{q\phi}{k_B T}\right)$$

By finite difference,

$$\frac{d}{dx} \left( \varepsilon(x) \frac{d}{dx} \right) \rightarrow A = \begin{pmatrix} 1 & 0 & \dots & \dots & \dots & \dots & \dots & \dots & \dots & \dots \\ \varepsilon_1 & -2\varepsilon_1 & \varepsilon_1 & & & & & & & \\ & \ddots & \ddots & \ddots & \ddots & \ddots & \ddots & \ddots & \ddots & \\ & \varepsilon_1 & -2\varepsilon_1 & \varepsilon_1 & & & & & & \\ & & \varepsilon_1 & -\varepsilon_1 & -\varepsilon_2 & \varepsilon_2 & & & & \\ & & & \varepsilon_2 & -2\varepsilon_2 & \varepsilon_2 & & & & \\ & & & & \ddots & \ddots & \ddots & \ddots & \ddots & \\ & & & & \varepsilon_2 & -2\varepsilon_2 & \varepsilon_2 & & & \\ & & & & & \varepsilon_2 & -\varepsilon_1 & -\varepsilon_2 & \varepsilon_1 & \varepsilon_1 \\ & & & & & & \varepsilon_1 & -2\varepsilon_1 & & \\ & & & & & & & \ddots & \ddots & \ddots \\ & & & & & & & \varepsilon_1 & -2\varepsilon_1 & \varepsilon_1 \\ & & & & & & & \dots & 0 & 1 \end{pmatrix}$$

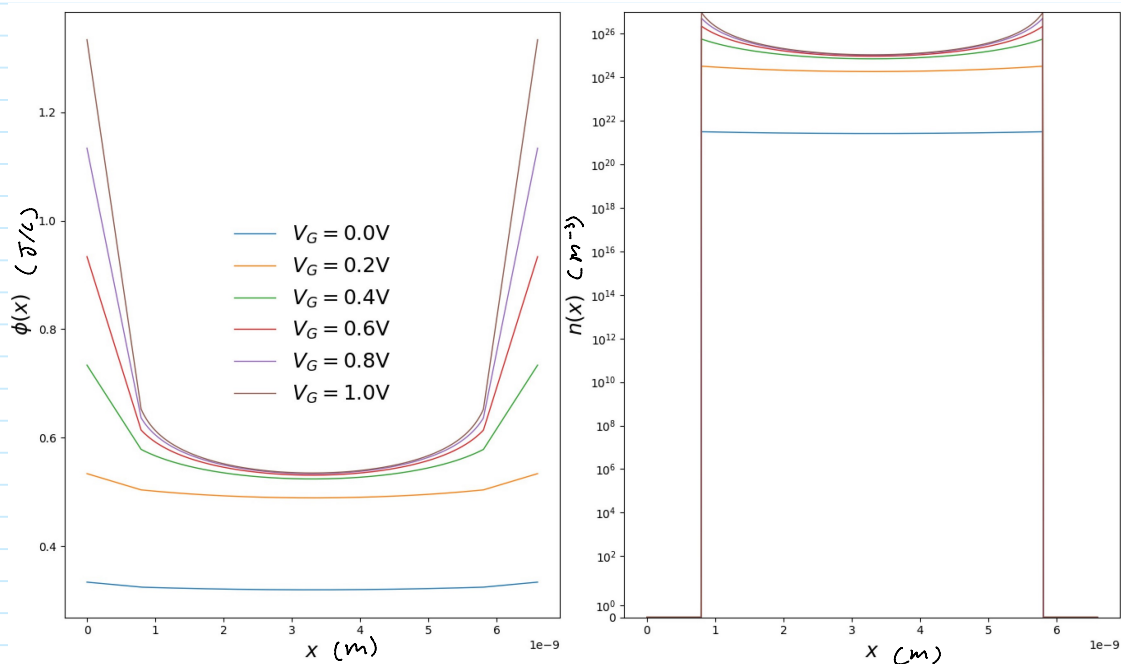
$$b(x) = (\Delta x)^2 \begin{pmatrix} \phi_0 + V_G \\ \vdots \\ 0 \\ \frac{\varepsilon_1 N_{acc}}{2} + \frac{\varepsilon_2}{2} (n(x) - p(x)) \\ \varepsilon_2 N_{acc} + \varepsilon_2 (n(x) - p(x)) \\ \vdots \\ \varepsilon_2 N_{acc} + \varepsilon_2 (n(x) - p(x)) \\ \frac{\varepsilon_1 N_{acc}}{2} + \frac{\varepsilon_2}{2} (n(x) - p(x)) \\ 0 \\ \vdots \\ \phi_0 + V_G \end{pmatrix} \begin{matrix} \rightarrow x = t_1 \\ \\ \\ \rightarrow x = t_1 + t_2 \end{matrix}, \quad \phi(x) = \begin{pmatrix} \phi_1 \\ \vdots \\ \phi_N \end{pmatrix}$$

\* Algorithm with Newton method



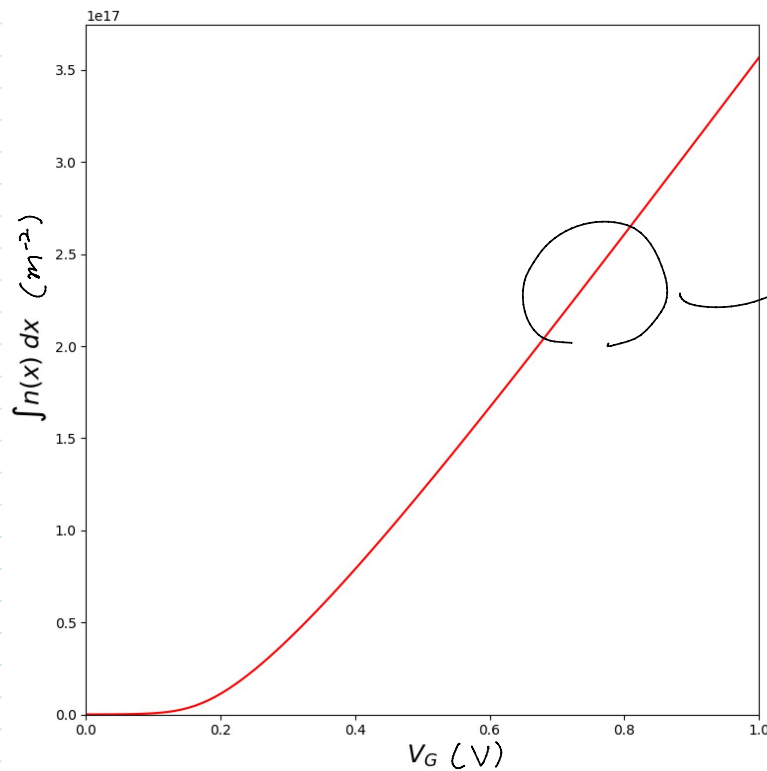
Results.

$$\phi_0 = 0.33374 \text{ V}, \quad N = 800, \quad N_{acc} = 10^{24} \text{ m}^{-3}, \\ t_1 = 0.8 \text{ nm}, \quad t_2 = 5 \text{ nm}, \quad \varepsilon_1 = 3.9\varepsilon_0, \quad \varepsilon_2 = 11.7\varepsilon_0, \quad T = 300 \text{ K}.$$



$n(\frac{L}{2})$ 은  $V_G$ 가 커져도  $\sim 10^{25} \text{ m}^{-3}$  에서 수렴한다. 하지만 interface에서 electron density가 급격하게 커짐을 알 수 있다.

Newton method를 이용하면 HW 6. 와 다르게 발생하는 문제가 사라진다.



∴ integrated electron density를  $V_G$ 에 따라 보았다.

